NSN 5962-01-361-6514

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view Online at https://aerobasegroup.com/nsi//5962-01-561-6514
Body Length:
Between 0.442 inches and 0.460 inches
Body Width:
Between 0.442 inches and 0.460 inches
Body Height:
Between 0.060 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and programmed and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
C-4 mil-m-38510
Current Rating Per Characteristic:
180.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Registerd and-or logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds delay
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
28 leadless

N/a

Shelf Life:

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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